

2023 IEEE International Symposium on Applications of Ferroelectrics (ISAF 2023)

**Cleveland, Ohio, USA
23 – 27 July 2023**



**IEEE Catalog Number: CFP23ISA-POD
ISBN: 978-1-6654-6324-9**

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IEEE Catalog Number:	CFP23ISA-POD
ISBN (Print-On-Demand):	978-1-6654-6324-9
ISBN (Online):	978-1-6654-6323-2
ISSN:	1099-4734

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